

Product specification Supersedes data of 1997 Feb 19 IC24 Data Handbook 1998 May 20



HILIP

74LV175

FEATURES

- Optimized for low voltage applications: 1.0 to 3.6 V
- Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- Typical V_{OLP} (output ground bounce) < 0.8 V at V_{CC} = 3.3 V, $T_{amb} = 25^{\circ}C$
- Typical V_{OHV} (output V_{OH} undershoot) > 2 V at V_{CC} = 3.3 V, $T_{amb} = 25^{\circ}C$
- Four edge-triggered D flip-flops
- Output capability: standard
- I_{CC} category: MSI

DESCRIPTION

The 74LV175 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT175.

The 74LV175 has four edge-triggered, D-type flip-flops with individual D inputs and both Q and \overline{Q} outputs. The common clock (CP) and master reset (\overline{MR}) inputs load and reset (clear) all flip-flops simultaneously.

The register is fully edge-triggered. The state of each D input, one set-up time prior to the LOW-to-HIGH clock transition, is transferred to the corresponding output (Q_n) of the flip-flop.

All Q_n outputs will be forced LOW independently of clock or data inputs by a LOW voltage level on the $\overline{\mathsf{MR}}$ input.

The device is useful for applications where both the true and complement outputs are required and the clock and master reset are common to all storage elements.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay CP to Q_{n}, \overline{Q}_{n} MR to Q_{n}, \overline{Q}_{n}	C _L = 15 pF; V _{CC} = 3.3 V	16 14	ns ns
f _{max}	Maximum clock frequency	7	77	MHz
Cl	Input capacitance		3.5	pF
C _{PD}	Power dissipation capacitance per flip-flop	$V_{CC} = 3.3 V$ V _I = GND to V _{CC} ¹	32	pF

NOTE:

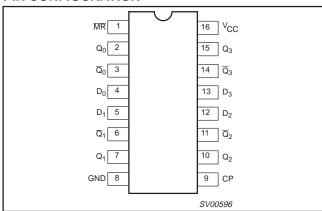
1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W) P_D = C_{PD} × V_{CC}² × f_i + \sum (C_L × V_{CC}² × f_o) where: f_i = input frequency in MHz; C_L = output load capacitance in pF; f_o = output frequency in MHz; V_{CC} = supply voltage in V;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of the outputs.}$

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
16-Pin Plastic DIL	–40°C to +125°C	74LV175 N	74LV175 N	SOT38-4
16-Pin Plastic SO	-40°C to +125°C	74LV175 D	74LV175 D	SOT109-1
16-Pin Plastic SSOP Type II	-40°C to +125°C	74LV175 DB	74LV175 DB	SOT338-1
16-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV175 PW	74LV175PW DH	SOT403-1

PIN CONFIGURATION

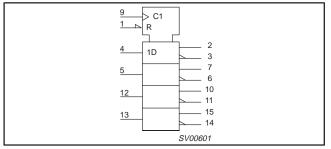


PIN DESCRIPTION

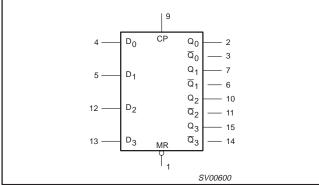
PIN NUMBER	SYMBOL	FUNCTION
1	MR	Master reset input (active LOW)
2, 7, 10, 15	Q_0 to Q_3	Flip-flop outputs
3, 6, 11, 14	\overline{Q}_0 to \overline{Q}_3	Complementary flip-flop outputs
4, 5, 12, 13	D_0 to D_3	Data inputs
8	GND	Ground (0 V)
9	СР	Clock input (LOW-to-HIGH, edge-triggered)
16	V _{CC}	Positive supply voltage

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LOGIC SYMBOL (IEEE/IEC)



LOGIC SYMBOL



FUNCTIONAL DIAGRAM D₀ Q₀ 4 2 \overline{Q}_0 3 Q D₁ 5 Q 6 FF0 Q2 to FF3 10 D_2 12 \overline{Q}_2 11

 D_3

MR CP

13

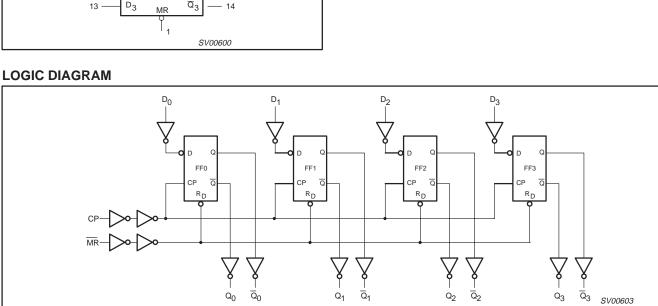
1 9 Q3

 \overline{Q}_3

15

14

SV00602



FUNCTION TABLE

OPERATING MODES		INPUTS	OUTPUTS		
OPERATING MODES	MR	СР	D _n	Q _n	<u>Q</u> n
Reset (clear)	L	Х	Х	L	Н
Load '1'	Н	\uparrow	h	Н	L
Load '0'	Н	\uparrow	I	L	Н

NOTES:

H = HIGH voltage level

h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition

L = LOW voltage level

I = LOW voltage level level one set-up time prior to the LOW-to-HIGH clock transition

 $\uparrow = LOW-to-HIGH clock transition$

X = don't care

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
V _{CC}	DC supply voltage	See Note 1	1.0	3.3	3.6	V
VI	Input voltage		0	-	V _{CC}	V
Vo	Output voltage		0	-	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 1.0V \text{ to } 2.0V$ $V_{CC} = 2.0V \text{ to } 2.7V$ $V_{CC} = 2.7V \text{ to } 3.6V$		_ _ _ _	500 200 100	ns/V

NOTE:

1. The LV is guaranteed to function down to V_{CC} = 1.0V (input levels GND or V_{CC}); DC characteristics are guaranteed from V_{CC} = 1.2V to V_{CC} = 3.6V.

ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134).

Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
±I _{IK}	DC input diode current	$V_{\rm I} < -0.5 \text{ or } V_{\rm I} > V_{\rm CC} + 0.5 V$	20	mA
±І _{ОК}	DC output diode current	$V_{\rm O}$ < -0.5 or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5V	50	mA
±lo	DC output source or sink current – standard outputs	$-0.5V < V_O < V_{CC} + 0.5V$	25	mA
±I _{GND} , ±I _{CC}	DC V _{CC} or GND current for types with -standard outputs		50	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{tot}	Power dissipation per package –plastic DIL –plastic mini-pack (SO) –plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

 Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC CHARACTERISTICS FOR THE LV FAMILY

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

					LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	-4	0°C to +8	5°C	-40°C to	o +125°C	
			MIN	TYP ¹	MAX	MIN	MAX	
		$V_{CC} = 1.2V$	0.9			0.9		
VIH	HIGH level Input voltage	$V_{CC} = 2.0V$	1.4			1.4		V
	l	V _{CC} = 2.7 to 3.6V	2.0			2.0		1
		$V_{CC} = 1.2V$			0.3		0.3	
VIL	LOW level Input voltage	$V_{CC} = 2.0 V$			0.6		0.6	V
	linage	V _{CC} = 2.7 to 3.6V			0.8		0.8	1
		V_{CC} = 1.2V; V_I = V_{IH} or $V_{IL;}$ – I_O = 100 μ A		1.2				
M	HIGH level output	$V_{CC} = 2.0V; V_I = V_{IH} \text{ or } V_{IL;} - I_O = 100 \mu A$	1.8	2.0		1.8		
V _{OH}	voltage; all outputs	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL;} - I_O = 100 \mu A$	2.5	2.7		2.5		1
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} - I_O = 100 \mu A$	2.8	3.0		2.8		1
V _{OH}	HIGH level output voltage; STANDARD outputs	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 6mA$	2.40	2.82		2.20		v
		V_{CC} = 1.2V; V_I = V_{IH} or V_{IL} ; I_O = 100 μ A		0				
M	LOW level output	V_{CC} = 2.0V; V_I = V_{IH} or V_{IL} ; I_O = 100 μ A		0	0.2		0.2	
V _{OL}	voltage; all outputs	V_{CC} = 2.7V; V_I = V_{IH} or V_{IL} ; I_O = 100 μ A		0	0.2		0.2	7 °
		V_{CC} = 3.0V; V_{I} = V_{IH} or $V_{IL;}$ I_{O} = 100 μA		0	0.2		0.2	
V _{OL}	LOW level output voltage; STANDARD outputs	V_{CC} = 3.0V; V_{I} = V_{IH} or $V_{IL;}$ I_{O} = 6mA		0.25	0.40		0.50	v
lı	Input leakage current	V_{CC} = 3.6V; V_{I} = V_{CC} or GND			1.0		1.0	μA
I _{CC}	Quiescent supply current; MSI	$V_{CC} = 3.6V; V_I = V_{CC} \text{ or GND}; I_O = 0$			20.0		160	μA
ΔI_{CC}	Additional quiescent supply current per input	$V_{CC} = 2.7V$ to 3.6V; $V_1 = V_{CC} - 0.6V$			500		850	μA

NOTE:

1. All typical values are measured at $T_{amb} = 25^{\circ}C$.

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AC CHARACTERISTICS

 $\text{GND} = \text{OV}; \ t_{\text{f}} = t_{\text{f}} \leq \text{2.5ns}; \ \text{C}_{\text{L}} = \text{50pF}; \ \text{R}_{\text{L}} = 1 \text{K} \Omega$

			CONDITION			LIMITS				
SYMBOL	PARAMETER	WAVEFORM			40 to +85			+125 °C	UNIT	
			V _{CC} (V)	MIN	TYP ¹	MAX	MIN	MAX		
			1.2		100					
	Propagation delay	Figures 1	2.0		34	65		77		
t _{PHL} /t _{PLH}	CP to $\overline{Q}_{n}, \overline{Q}_{n}$	Figures 1	2.7		25	48		56	ns	
			3.0 to 3.6		19 ²	38		45		
			1.2		90					
	$\mathcal{A}_{PLH} \frac{Propagation delay}{MR \text{ to } Q_{n}, \overline{Q}_{n}} \qquad Fig$		2.0		31	58		70		
$\frac{1}{MR} \text{ to } Q_{n_{1}} \overline{Q}_{n}$		Figures 2	2.7		23	43		51	ns	
			3.0 to 3.6		17 ²	34		41		
	Clock pulse width tw HIGH or LOW		2.0	34	14		41			
tw		Figures 1	2.7	25	10		30		ns	
			3.0 to 3.6	20	8 ²		24			
			2.0	34	14		41			
tw Master reset pulse	Master reset pulse width LOW	Figures 2	2.7	25	9		30		ns	
			3.0 to 3.6	20	7 ²		24			
				1.2		-60				
	Removal time		2.0	5	-20		5		ns	
t _{rem}	MR to CP	Figures 2	2.7	5	-15		5			
			3.0 to 3.6	5	-12 ²		5			
			1.2		5					
	Set-up time		2.0	22	2		26			
t _{su}	D _n to CP	Figures 3	2.7	16	2		19		ns	
			3.0 to 3.6	13	1 ²		15			
			1.2		-5					
	Hold time		2.0	5	-1		5			
t _h	D _n to CP	Figures 3	2.7	5	0		5		ns	
			3.0 to 3.6	5	0 ²		5			
			2.0	14	40		12			
f _{max}	Maximum clock pulse frequency	Figures 1 2.7 19 58 16			MHz					
	p = : : : : : : : : : : : : : : : : : :		3.0 to 3.6	24	70 ²		20			

NOTES:

1. Unless otherwise stated, all typical values are measured at $T_{amb} = 25^{\circ}C$. 2. Typical values are measured at $V_{CC} = 3.3 \text{ V}$.

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AC WAVEFORMS

 V_M = 1.5 V at $V_{CC} \ge 2.7$ V; V_M = 0.5 V \times V_{CC} at $V_{CC} < 2.7$ V. V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

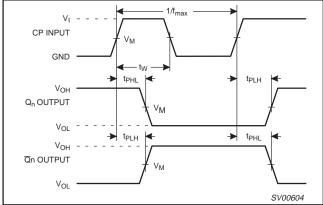


Figure 1. Clock (CP) to outputs (Q_n, \overline{Q}_n) propagation delays, the clock pulse width and the maximum clock pulse frequency.

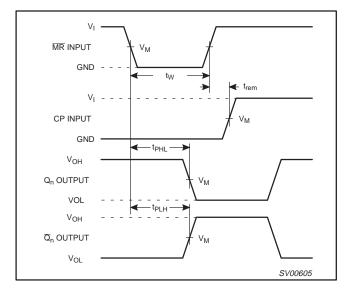


Figure 2. Master reset (MR) pulse width, the master reset to outputs (Q_n, \overline{Q}_n) propagation delay and master reset to clock (CP) removal time.

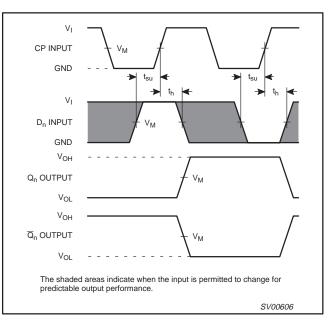


Figure 3. Data set-up and hold times for data input (D_n).

TEST CIRCUIT

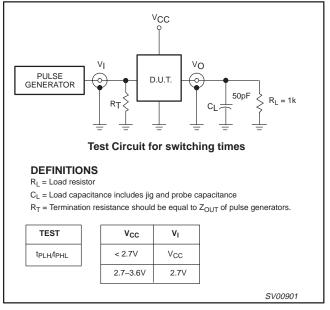
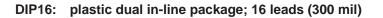
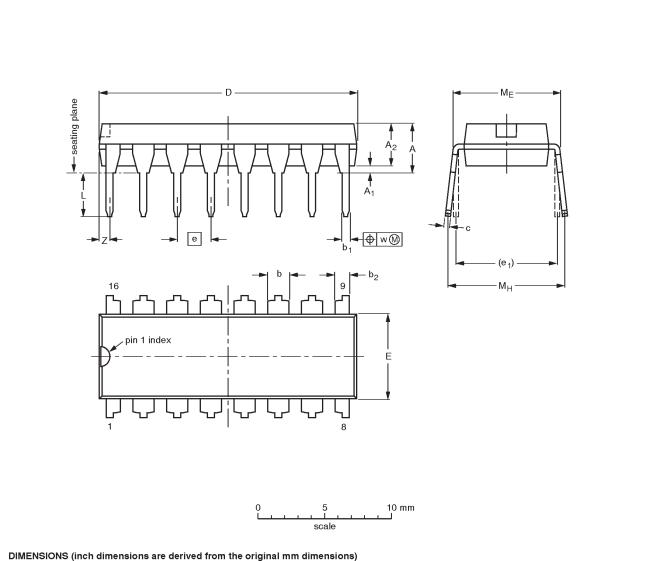


Figure 4. Load circuitry for switching times.





UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	c	о ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.030

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

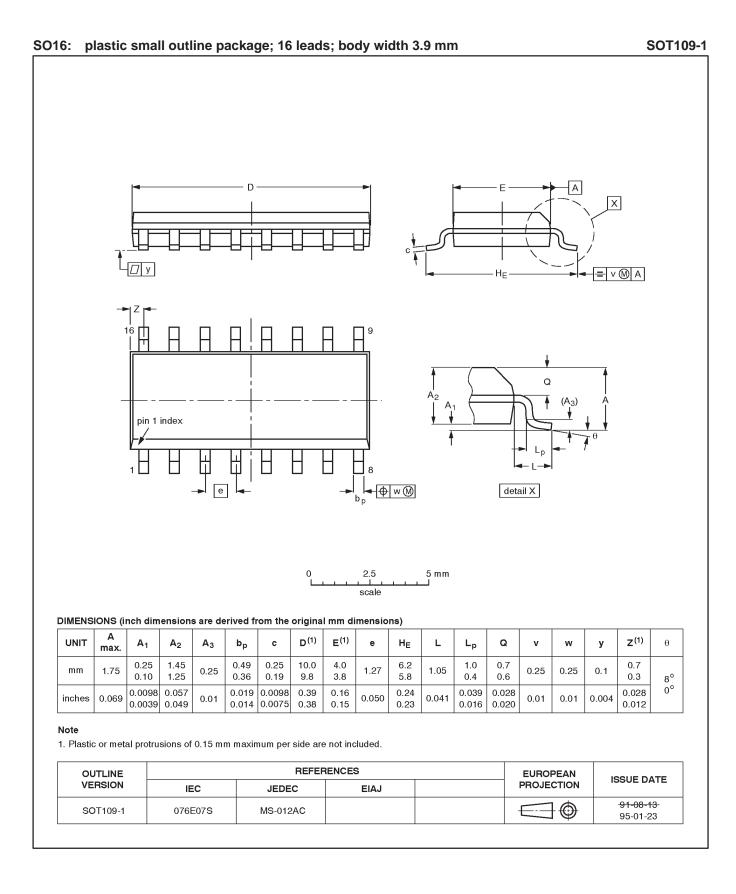
OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT38-4						-92-11-17 95-01-14

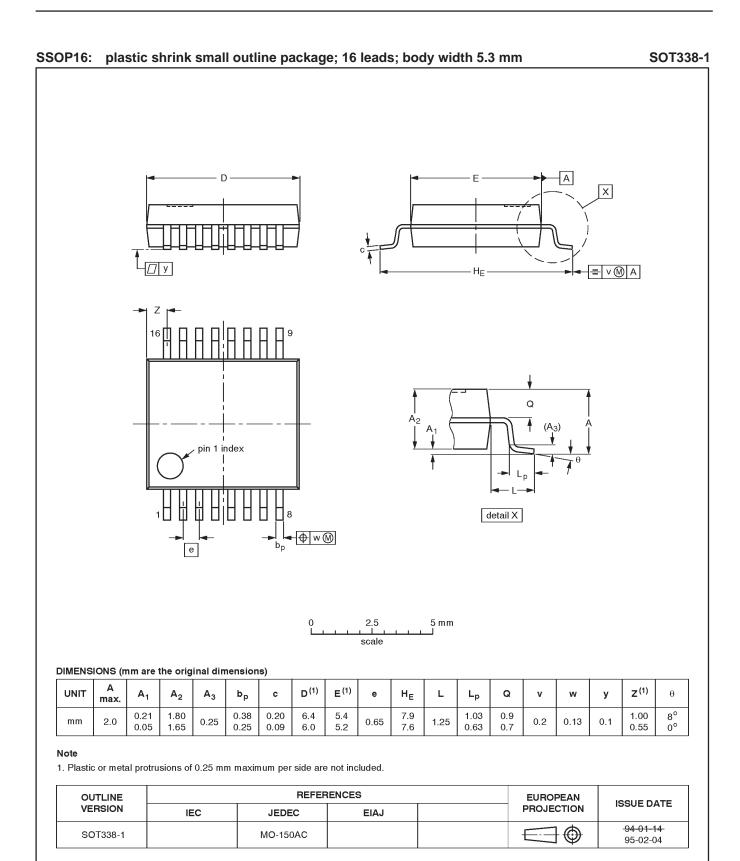
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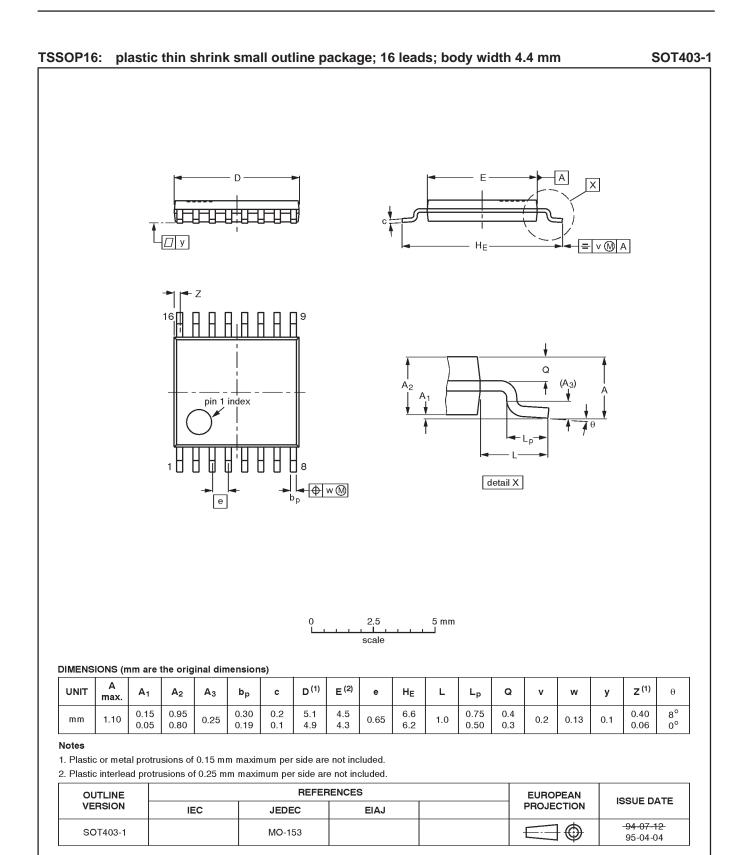
SOT38-4

Philips Semiconductors

Quad D-type flip-flop with reset; positive-edge trigger







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NOTES

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	DEFINITIONS						
Data Sheet Identification Product Status Definition		Definition					
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